

C2N General Seminar

Friday March 12th 2020- 10h 00

"III-V and IV-IV heterogeneous integration on silicon at the nanoscale"

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Link: https://us02web.zoom.us/j/88274596539

In this presentation, we will focus on the general problematic of heterogeneous integration on silicon of lattice mismatched materials, such as GaAs and

germanium. After a brief introduction to this problem, I will present the concept of integration that we have developed to avoid the formation of crippling defects in this type of heterostructures (dislocations and antiphase domains). The concept adopted consists in carrying out growth from limited size seeds (<100nm) by partial deoxidation or localized etching of the substrate. I will then focus more particularly on the monolithic integration

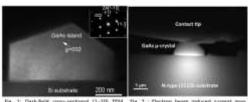


Fig. 1: Dark-field cross-sectional (1–10) TEM. Fig. 1: Electron beam induced images of GaAs microcrystal grown on (111) St. superimposed with the SEAS str. waters showing no dislocation rise antiphase of GaAs microcrystal grown in the Control of GaAs microcrystal grown in

by lateral growth of GaAs micro-crystals from nanometric openings made through a thin layer of silica. We will then see that the electric current can cross the thin oxide zone separating the GaAs microcrystals and the silicon substrate, paving the way for the production of electrically injected optical components.



Charles Renard has performed his Ph.D. at Alcatel-Thales III-V Lab on the growth of Sb/As heterostructures for optoelectronic applications. Then he spent two years as a post-doctoral fellow at IEF on the growth of nanostructures for ultimate MOSFET. In 2008 he spent 6 months at IMEC, within the Ge III-V explore program. Since 2008, he is CNRS scientific researcher at IEF (now C2N) where he is working on hybrid integration of IV-IV materials on Si, since 2012 he expanded this study to III-V materials on Si. He obtained physics HDR degree in 2019.



